

Equations To Remember:

Threshold Gain: $g_{th} = \frac{\alpha_i + \alpha_m}{T} = \frac{\alpha_i}{T} + \frac{1}{2TL} \ln \frac{1}{R_1 R_2}$

Quantum Efficiency: $QE = \frac{\alpha_m}{\alpha_i + \alpha_m}$

Quality Factor: $Q = \frac{\omega_0}{\Delta\omega} = \omega_0 T_p$

$\frac{\eta}{\alpha_{tot}}$

Energy + Momentum Conservation: $E_g + \frac{\hbar^2 k^2}{2m_r^*} = \hbar\omega$

Electron Concentration: $n = \int_{E_c}^{\infty} dE f_n(E) \rho(E)$ where $f_n(E) = \frac{1}{1 + e^{(E-F_n)/kT}}$

Electron Concentration in 3D: $\begin{cases} F_n \ll E_c \Rightarrow n = N_c e^{F_n - E_c/kT} \\ F_n \gg E_c \Rightarrow n = N_c \frac{4}{3\sqrt{\pi}} \left(\frac{F_n - E_c}{kT} \right)^{3/2} \end{cases}$

Effective DOS: $N_c = 2 \left(\frac{\pi m_e^* kT}{2\pi \hbar^2} \right)^{3/2}$

Electron Concentration in 2D: $\begin{cases} F_n \ll E_{c1} \Rightarrow N \approx \left(\frac{m_e^* kT}{\pi \hbar^2 L_z} \right) e^{-\frac{E_{c1} - F_n}{kT}} \\ F_n \gg E_{c1} \Rightarrow N = \frac{m_e^*}{\pi \hbar^2 L_z} (F_n - E_{c1}) \end{cases}$

Density of States in 3D: $\rho_e^{3D}(E) = \frac{m_e^*}{\hbar^3 \pi^2} \sqrt{\frac{2m_e^* (E - E_c)}{\hbar^2}}$

in 2D: $\rho_e^{2D}(E) = \frac{m_e^*}{\pi \hbar^2 L_z} \sum_{m=1}^{\infty} H(E - E_m)$ $E_m = E_c + \frac{\hbar^2 \pi^2}{2m_e^*} \left(\frac{m}{L_z} \right)^2$

in 1D: $\rho_e^{1D}(E) = \frac{1}{4\pi^3 L_x L_y} \sqrt{\frac{m_e}{2\hbar}} \sum_{m,n} \frac{1}{\sqrt{E - E_c - E_{mn}}}$

in 0D: $\rho_e^{0D}(E) = \frac{2}{V} \sum_{m,n,q} \delta_{E, E_c + E_{mnq}}$

Schrodinger's Equation: $\hat{H} \psi(\vec{r}, t) = i\hbar \frac{\partial}{\partial t} \psi(\vec{r}, t)$ where $\hat{H} = \frac{p^2}{2m} + V(\vec{r}, t)$; $\vec{p} = i\hbar \vec{\nabla}$

Infinite Square Well: $\psi(\vec{r}, t) = e^{i(k_x x + k_y y)} e^{-i\omega t} \begin{cases} A \sin(k_z z) \\ A \cos(k_z z) \end{cases}$ $E_n = \frac{\hbar^2}{2m_e^*} \left(\frac{n\pi}{L_z} \right)^2$

Gaussian Beam: $w(z) = w_0 \sqrt{1 + \left(\frac{z}{z_0} \right)^2}$; $z_0 = \frac{\pi w_0^2}{\lambda}$; $R(z) = z \left(1 + \left(\frac{z_0}{z} \right)^2 \right)$

Fermi's Golden Rule: $W_{i \rightarrow f} = \frac{2\pi}{\hbar} |H'_{fi}|^2 \delta(E_f - E_i - \hbar\omega) + \frac{2\pi}{\hbar} |H'_{fi}|^2 \delta(E_f - E_i + \hbar\omega)$

↳ FGR for Many Energy levels: $W_{i \rightarrow f} = \frac{2\pi}{\hbar} |H'_{fi}|^2 \rho_f(E_f) \delta(E_f - E_i - \hbar\omega) + \dots$

Matrix Element: $H'_{ba} = -\frac{eA_0}{2m_0} \hat{e} \cdot \langle b | \mathbf{p} | a \rangle$

Dipole Approximation: $H'_{ba} \approx -e\bar{E} \cdot \langle b | \mathbf{r} | a \rangle$

Absorption/Gain Spectrum: $\alpha^{3D}(\hbar\omega) = -\frac{2\pi}{\hbar} |H'_{ba}|^2 \rho_r^{3D}(\hbar\omega - E_g) f_g(\hbar\omega - E_g)$

$\alpha^{2D}(\hbar\omega) = -\frac{2\pi}{\hbar} |H'_{ba}|^2 \rho_r^{2D} f_g(\hbar\omega - E_g)$

Bernard-Durafoury gain condition: $E_g < \hbar\omega < \Delta F$

Excess Electron/Hole Energy: $\begin{cases} E_b - E_c = (\hbar\omega - E_g) \frac{m_r^*}{m_e^*} \\ E_v - E_a = (\hbar\omega - E_g) \frac{m_r^*}{m_h^*} \end{cases}$

Spontaneous Emission Rate: $\Gamma_{21}^{spont}(E_{21}) = \frac{8\pi n^2 E_{21}^2}{h^3 c^3} c_0 |\hat{e} \cdot \bar{p}_{cv}| \rho_r(\hbar\omega - E_g) \frac{f_e}{f_g}$

Bose-Einstein Distribution: $\frac{1}{e^{\hbar\omega/kT} - 1}$

Lorentzian: $g(\Delta E) = \frac{1}{\pi} \frac{\frac{\Gamma}{2}}{\Delta E^2 + (\frac{\Gamma}{2})^2}$

Maximum Intersubband Transition: $\alpha_{max} = \frac{\pi\omega}{nc\epsilon_0} \frac{1}{\pi} \frac{1}{\Gamma/2} \frac{1}{\pi\hbar^2 L_z} E_{21}^c |u_{21}|^2$

Diode IV characteristics: $I = I_0 (e^{qV/kT} - 1)$ $I_0 = q \left(\frac{D_n}{L_n} n_{p0} + \frac{D_p}{L_p} p_{n0} \right)$

V Number: $V = k_0 d \sqrt{n_1^2 - n_2^2}$ Single Mode Condition: $V < \pi$

Confinement Factor: $\Gamma \approx \frac{V^2}{2+V^2}$

Effective Index: $k_z = n_{eff} k_0$

Cavity Modes: $m \frac{c}{2n_{\text{eff}}L} = f$ Mode Spacing: $\Delta f = \frac{c}{2n_{\text{eff}}L} \frac{1}{1 + \frac{f}{n_{\text{eff}}} \frac{dn_{\text{eff}}}{df}}$

Rate Equations:
$$\begin{cases} \frac{dN}{dt} = \frac{\eta_i I}{qV} - \frac{N}{\tau} - g(N) v_g S \\ \frac{dS}{dt} = \Gamma g(N) v_g S - \frac{S}{\tau_p} + \Gamma \beta R_{sp} \end{cases}$$

$\left\{ \begin{array}{l} \frac{dN}{dt} = \text{Amount of charge injected} - \text{recombining charge} - \text{charge lost due to stimulated emission} \\ \frac{dS}{dt} = \text{Photons gained due to stimulated emission} - \text{photons lost due to lifetime} + \text{Photons gained due to spontaneous emission} \end{array} \right.$

Threshold current: $I_{th} = \frac{qV}{\eta_i} \frac{N_{th}}{\tau}$

Output Power above threshold: $P_{out} = \frac{\hbar \omega}{q} \eta_i \eta_o (I - I_{th})$

Relaxation Oscillation Frequency: $\omega_R^2 = \frac{v_g a S}{\tau_p}$

Direct Modulation Transfer Function: $H(\omega) = \frac{\omega_R^2}{\omega_R^2 - \omega^2 + j\omega\gamma}$

Transparency Condition: $\Delta F = E_g$

Ideal QW Transparency concentration: $N_{tr}^{ideal} = \frac{m_e^*}{\pi \hbar^2 L_z} k_B T \ln 2$

Strain Trend: lattice spacing $\uparrow E_g \downarrow$, lattice spacing $\downarrow E_g \uparrow$

⚠ Want Compressive strain for Lasers, Tensile strain for Amplifiers

P-i-n Photocurrent: $I_{ph} = \eta \frac{q}{\hbar \omega} P_{opt}$

Ramo's Theorem: Current only exists while charge is moving) $i(t) = \frac{qv(t)}{d}$

P-i-n Temporal Resonse: $\tau = \frac{d}{v_h} + R \frac{\epsilon A}{d}$

P-i-n Efficiency: $\eta = \eta_i (1 - e^{-\alpha d})$

P-i-n 3dB frequency: $f_{3dB} = \frac{\nu_n}{2\pi} \frac{1}{d}$

P-i-n Bandwidth-Efficiency tradeoff: $\eta f_{3dB} \approx \frac{\alpha \eta_i \nu_n}{2\pi}$

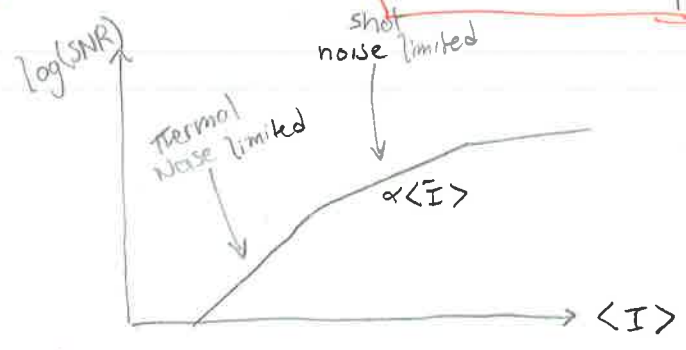
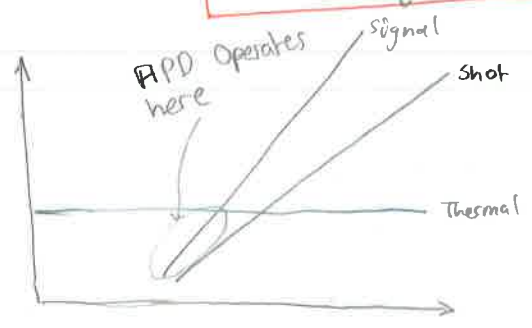
Photoconductor Current: $\Delta I = P_{opt} \left[\frac{q}{h\nu} \right] \frac{\tau_n}{\tau_t}$

Photoconductive Gain: $\frac{\tau_n}{\tau_t}$

Photoconductor 3dB Bandwidth: $f_{3dB} = \frac{1}{2\pi} \frac{1}{\tau_n}$

Shot Noise: $\langle i_n^2 \rangle = 2q \langle I \rangle \Delta \nu$

Thermal Noise: $\langle i_n^2 \rangle = \frac{4kT \Delta \nu}{R}$

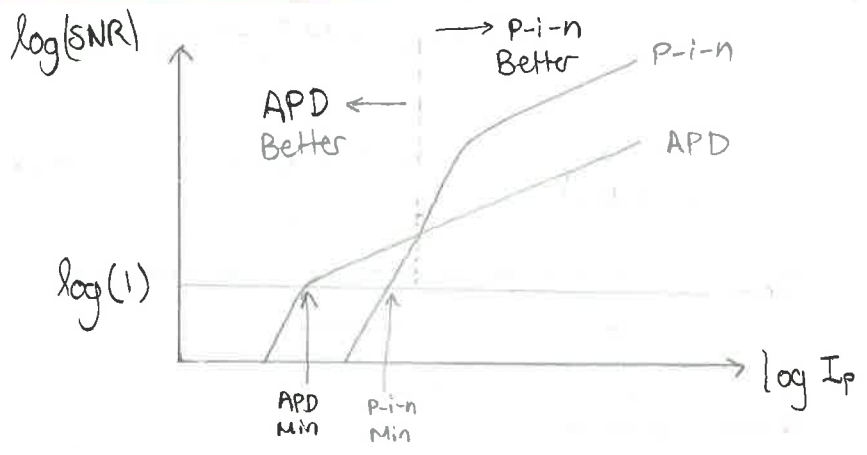


Multiplication Factor: $M = \frac{J}{J_n(0)} = \frac{1-k}{e^{-(1-k)\alpha_n W} - k}$ $k = \frac{\beta_e}{\alpha_n} < 1$

Noise Factor: $F = \frac{\langle M^2 \rangle}{\langle M \rangle^2} = k \langle M_n \rangle + (1-k) \left(2 - \frac{1}{\langle M_n \rangle} \right)$ $k=1 \Rightarrow \text{instability}$

$SNR = \frac{\frac{1}{2} I_{ph}^2 \langle M \rangle^2}{2q(I_{ph} + I_{dark}) F \langle M \rangle^2 \Delta \nu + 4kT \Delta \nu / R}$

Note: $\langle M \rangle^2 = 1 = F$ for Photodiode



Snells law: $n_1 \sin \theta_1 = n_2 \sin \theta_2$

Fermat's Principle: $OPL = \int_{\text{path}} n(r) ds$ is minimized

Critical angle: $n_1 \sin \theta_{\text{crit}} = n_2$

Spherical ("curved") surface: $\begin{pmatrix} 1 & 0 \\ \frac{n_1 - n_2}{R n_2} & \frac{n_1}{n_2} \end{pmatrix} = A(R)$

Thin lens: $\begin{pmatrix} 1 & 0 \\ -\frac{1}{f} & 1 \end{pmatrix} = A(R_2) A(R_1)$

Lensmaker's Formula: $\frac{1}{f} = \frac{n_2 - n_1}{n_1} \left(\frac{1}{R_1} - \frac{1}{R_2} \right)$

Image Formation: $\left\{ \begin{array}{l} \text{Lateral Magnification: } M_T \equiv \frac{h_i}{h_o} = -\frac{f}{x_o} = -\frac{x_i}{f} \\ \text{Imaging Condition: } x_o x_i = f^2 \Rightarrow \frac{1}{s_o} + \frac{1}{s_i} = \frac{1}{f} \end{array} \right.$

Numerical Aperture: $NA = n \sin \theta$ f-number: $f/\# = \frac{1}{2NA}$

Cauchy's Equation: $n(\lambda) = A + \frac{B}{\lambda^2} + \frac{C}{\lambda^4} + \dots$

Abbe Number: $V = \frac{n_D - 1}{n_F - n_C}$

Point Spread Function: $I(x, y) = \overset{\text{Image}}{O(x, y)} \otimes \text{PSF}(x, y)$

Rayleigh Resolution Criterion: $R = 1.22 \frac{\lambda}{2n \sin \theta_{\text{max}}}$

Abbe diffraction Limit: $d = \frac{\lambda}{2n \sin \theta_{\text{max}}}$

Optical Transfer Function: $\mathcal{F}\{\text{PSF}(x, y)\} = H(f_x, f_y)$

Modulation transfer function: $\text{MTF} = |H(f_x, f_y)|$

Huygens-Fresnel Principle:

$$g(x', y') = \frac{z}{i\lambda} \iint dx dy g(x, y) \frac{e^{ikr}}{r^2}$$

$$r = \sqrt{z^2 + (x'-x)^2 + (y'-y)^2}$$

Fraunhofer Approximation:

$$G(x', y') = \frac{e^{ikz} e^{i\frac{k}{2z}(x'^2+y'^2)}}{i\lambda z} \iint dx dy g(x, y) e^{-i\frac{2\pi}{\lambda z}(x'x+y'y)}$$

$$z \gg \frac{k(x^2+y^2)}{2}$$

Linearity: $H(g_1) + H(g_2) = H(g_1 + g_2)$; $H(ag_{in}) = aH(g_{in})$

Fresnel Propagation:

$$G(x', y') = \frac{e^{ikz}}{i\lambda z} \iint dx dy g(x, y) e^{i\frac{k}{2z}[(x'-x)^2 + (y'-y)^2]}$$

Talbot Distance:

$$z_n = \frac{2nL^2}{\lambda}$$

$n=1, 2, \dots$ $L \equiv$ period of object grating

2f FT lens system:

$$g_{out}(x', y'; f) \propto \iint g_{in}(x, y) e^{-i2\pi(x\frac{x'}{2f} + y\frac{y'}{2f})} dx dy$$

Autocorrelation:

$$g(x) * g(x) = \int g(x') g(x'-x) dx'$$

Power Spectrum:

$$\mathcal{F}\{g * g\} = \tilde{G} \tilde{G}^* = |G|^2$$

4F system

$$g_{out} = g_{in}\left(-\frac{f_2}{f_1}x\right)$$

Parseval's Theorem:

$$\int_{-\infty}^{\infty} |g(x)|^2 dx = \int_{-\infty}^{\infty} |\tilde{G}(f_x)|^2 df_x$$

Fresnel Propagation as Fourier Transforms: $G(x', y') = g(x, y) \otimes h(x, y; z)$

where $h(x, y; z) = \frac{e^{ikz}}{i\lambda z} e^{i\frac{k}{2z}[(x'-x)^2 + (y'-y)^2]}$

Thus

$$G(x', y') = \mathcal{F}^{-1}\{\mathcal{F}\{g(x, y)\} H(u, v)\}$$

where

$$H(u, v) = \mathcal{F}\{h(x, y; z)\} = \frac{e^{ikz}}{i\lambda z} e^{-i\pi\lambda z(u^2 + v^2)}$$